



DM-TFT24-405

2.4" 240 × 320 TFT LCD DISPLAY PANEL WITH RESISTIVE TOUCH -MCU



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1 Revision History

Date	Changes
2019-10-09	First release

2 Main Features

Item	Specification	Unit
Diagonal Size	2.4	inch
Display Element	TFT active matrix	-
Display mode	Transmissive/ Normally White	-
Pixel arrangement	RGB vertical stripe	-
Display Colors	65K	Colors
Resolution	240(RGB) x 320	pixel
Controller IC	ST7789V	-
Interface	8/16 Bit MCU	-
Active Area	36.72 x 48.96	mm
Panel Dimension	42.72 x 60.26 x 3.8	mm
Pixel Pitch	0.153 x 0.153	mm
Viewing angle	12:00	o'clock
Weight	TBD	g



3 Pin Description

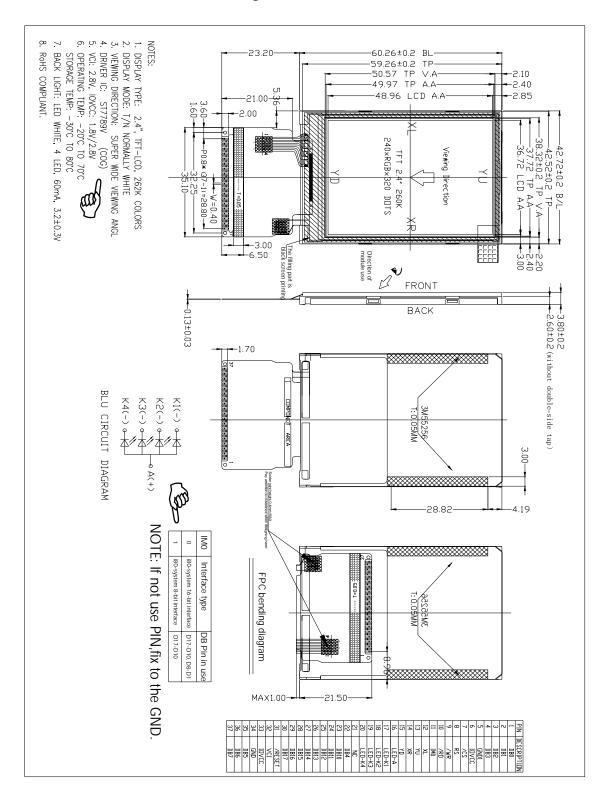
3.1 Panel Pin Description

Pin No.	Symbol	Function Description
1	DB0	·
2	DB1	DATA BUS.
3	DB2	If not used pins must be fixed to GND level.
4	DB3	
5	GND	GND
6	IOVCC	POWER SUPPLY
7	/CS	Chip select input pin
8	RS	A register select signal
9	/WR	Write enable clock input pin
10	/RD	Read enable clock input pin
11	IM0	Interface select.
12	XL	Touch panel LIFT Glass Terminal
13	YU	Touch panel Top Film Terminal
14	XR	Touch panel Right Glass Terminal
15	YD	Touch panel Bottom Film Terminal
16	LED-A	Backlight+
17	LED-K1	Backlight-
18	LED-K2	Backlight-
19	LED-K3	Backlight-
20	LED-K4	Backlight-
21	NC	NC
22	DB4	
23	DB10	
24	DB11	
25	DB12	DATA BUS
26	DB13	If not used pins must be fixed to GND level.
27	DB14	If not used pins must be fixed to GND level.
28	DB15	
29	DB16	_
30	DB17	
31	/RESET	HARDWARE RESET PIN
32	VCI	POWER SUPPLY
33	IOVCC	POWER SUPPLY
34	GND	GND
35	DB5	DATA BUS DB5
36	DB6	If not used pins must be fixed to GND level.
37	DB7	IT not used pins must be fixed to OND fevel.



4 Mechanical Drawing

4.1 Panel Mechanical Drawing





5 Optics & Electrical Characteristics

5.1 Optical Characteristics

Item	Symbol	Condition	Min	Тур	Max	Unit	Remark
C.I.E. (White)	(x)		0.253	0.303	0.353		
C.I.E. (Willie)	(y)		0.309	0.359	0.409	-	
C.I.E(Red)	(x)		0.581	0.631	0.681		
C.I.E(Red)	(y)	C-light	0.265	0.315	0.365	_	C.I.E.1931
C.I.E(Green)	(x)	C-light	0.261	0.311	0.361		C.I.E.1931
C.I.E(Green)	(y)		0.478	0.528	0.578	-	
C.I.E(Blue)	(x)		0.081	0.131	0.181		
C.I.E(Blue)	(y)		0.119	0.169	0.219	-	
Transmittance	T(%)	_	5.5	6.0	_	%	
(with Polarizer)	1(70)	_	J.J	0.0	_	70	
Contrast Ratio	CR	θ=0°	400	500	-	%	Note
Basmanas tima	Ton	25°C		20	30	****	
Response time	Toff	23 C	-	20	30	ms	
NTSC	S(%)		-	55	-	%	
	$\theta_{ m L}$		40	60	-		
View Angles	θ_{R}	CD > 10	40	60	-	0	
	θ_{T}	CR>10	45	50	-		
	θ_{B}		15	70	-		
Option View Direction		6 O'clock					

Measuring Condition

1. Measuring surrounding: dark room

2. Ambient temperature: 25±2°C

3. 15min. warm-up time.

Note: Definition of contrast ratio

Contrast ratio (CR)=

Luminance measured when LCD is on the "White"state

Luminance measured when LCD is on the "Black"state

"White state ":The state is that the LCD should driven by Vwhite.

"Black state": The state is that the LCD should driven by Vblack.

Vwhite:To be determined Vblack:To be determined.



5.2 Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Digital Supply Voltage	V_{DD}	-0.3	4.6	V
Digital interface Supply Voltage	$V_{ m DDIO}$	-0.3	4.6	V
Operating Temperature	Тор	-20	70	°C
Storage Temperature	T _{STG}	-30	80	°C

Note: Ta=25°C VSS=0V

5.3 DC Characteristics

Item	Symbol	Min	Тур.	Max	Unit
Digital Supply Voltage	$V_{ m DD}$	2.4	3.3	4.2	V
Digital interface Supply Voltage	$V_{ m DDIO}$	1.65	3.3	4.2	V
Normal mode Current consumption	I_{DD}	-	8	-	mA
Low Level Input Voltage	V _{IL}	GND	-	0.3 x V _{DDIO}	V
High Level Input Voltage	$V_{ m IH}$	$0.7 \times V_{DDIO}$	-	$V_{ m DDIO}$	V
Low Level Output Voltage	V_{OL}	GND	-	$0.2 \text{ x V}_{\text{DDIO}}$	V
High Level Output Voltage	V_{OH}	$0.8 \times V_{DDIO}$	-	$V_{ m DDIO}$	V

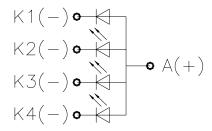
5.4 LED Backlight Characteristics

The back-light system is edge-lighting type with 4chips White LED

Parameter	Symbol	Min	Тур	Max	Unit	Remark
Forward voltage	$V_{\rm F}$	-	3.2	-	V	
Forward current	I_F	60	80	-	mA	
LCM Luminance	Lv	500	-	-	cd/m ²	
LED life time	Hr	50000			Hour	Note1,2
Uniformity	AVg	80			%	

Note1: LED life time (Hr) can be defined as the time in which it continues to operate under the condition: Ta=25±3 °C, typical IL value indicated in the above table until the brightness becomes less than 50%.

Note2: The "LED life time" is defined as the module brightness decrease to 50% original brightness at Ta=25°C and IL=80mA. The LED lifetime could be decreased if operating IL is larger than 80mA. The constant current driving method is suggested.

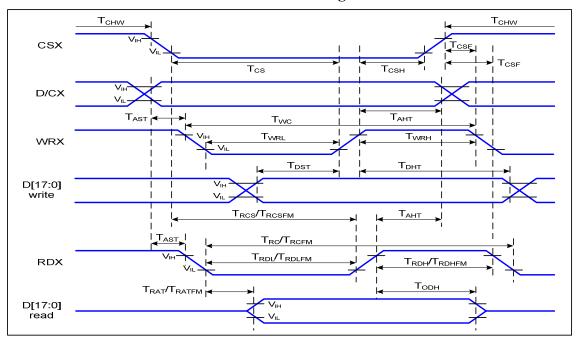


BLU CIRCUIT DIAGRAM



5.5 AC Characteristics

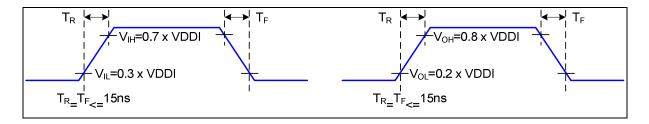
5.5.1 8080-Series MPU Parallel Interface Timing Characteristics



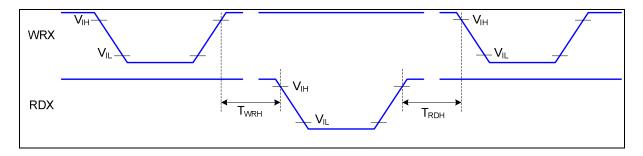
VDDI=1.65 to 3.3V, VDD=2.4 to 3.3V, AGND=DGND=0V, Ta= -30 to 70 °C

Signal	Symbol	Description	Min	Max	Unit	Note	
D/CX	T _{AST}	Address setup time	0	ı	ns		
D/CA	T_{AHT}	Address hold time(Write/Read)	10	-	ns		
	T_{CHW}	CSH "H" Pulse Width	0	-	ns		
	Tcs	Chip select setup time(Write)	10	-	ns		
CSX	T _{RCS}	Chip select setup time(Read ID)	45	-	ns		
CSA	T _{RCSFM}	Chip select setup time(Read FM)	355	-	ns		
	T _{CSF}	Chip select wait time(Write/Read)	10	-	ns		
	T _{CSH}	Chip select hold time	10	-	ns		
	Twc	Write cycle	66	-	ns		
WRX	Twrh	Control pulse H duration	15	-	ns		
	Twrl	Control pulse L duration		-	ns		
RDX	T_{RC}	Read cycle (ID)	160	-	ns		
(ID)	T_{RDH}	Control pulse H duration(ID)	90	-	ns	When read ID data	
(1D)	T_{RDL}	Control pulse L duration(ID)	45	-	ns		
RDX	T_{RCFM}	Read cycle (FM)	450	-	ns	When read from frame	
(FM)	T_{RDHFM}	Control pulse H duration(FM)	90	-	ns	memory	
(1 1/1)	T _{RDLFM}	Control pules L duration(FM)	355	-	ns	incinor y	
	T_{DST}	Data setup time	10	-	ns		
	T_{DHT}	Data hold time	10	-	ns		
D[170]	T_{RAT}	T _{RAT} Read access time(ID)		40	ns	ForCL=30pF	
	T _{RATFM}	Read access time(FM)	-	340	ns		
	Todh	Output disable time	20	80	ns		





Rising and Falling Timing for I/O Signal



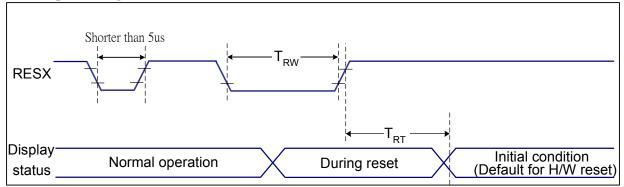
Write-to-Read and Read-to-Write Timing

Note: The rising time and falling time (Tr, Tf) of input signal and fall time are specified at 15 ns or less. Logic high and low levels are specified as 30% and 70% of VDDI for Input signals.



5.5.2 Display RESET Timing Characteristics

Reset input timing



VDDI=1.65 to 3.3V, VDD=2.4 to 3.3V, AGND=DGND=0V, Ta=-30 to 70°C

Related Pins	Symbol	Parameter	Min	Max	Unit
	TRW	Reset pulse duration	10	-	μs
RESX	TRT	Dagat asmaal	-	5(Note 1,5)	ms
	IKI	Reset cancel	-	120(Note 1,6,7)	ms

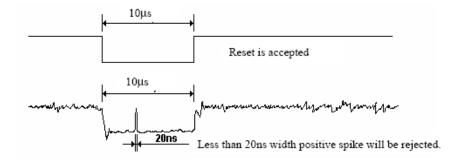
Note 1: The reset cancel includes also required time for loading ID bytes, VCOM setting and other settings from NVM (or similar device) to registers. This loading is done every time when there is HW reset cancel time (tRT) within 5 ms after a rising edge of RESX.

Note 2: Spike due to an electrostatic discharge on RESX line does not cause irregular system reset according to the table below:

RESX Pulse	Action
Shorter than 5µs	Reset Rejected
Longer than 9µs	Reset
Between 5µs and 9µs	Reset starts

Note 3: During the Resetting period, the display will be blanked (The display is entering blanking sequence, which maximum time is 120 ms, when Reset Starts in Sleep Out –mode. The display remains the blank state in Sleep In –mode.) and then return to Default condition for Hardware Reset.

Note 4: Spike Rejection also applies during a valid reset pulse as shown below:



Note 5: When Reset applied during Sleep In Mode

Note 6: When Reset applied during Sleep Out Mode.

Note 7:It is necessary to wait 5msec after releasing RESX before sending commands. Also Sleep Out command cannot be sent for 120msec



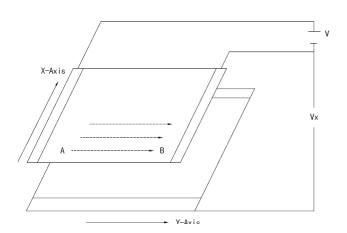
6 TP Feature

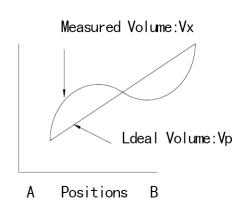
6.1 Conditions of use and storage

Item	Content of Test	Note
Temperature range upon operation	Humidity: 20%~90% non dew, condensation -20°C~70°C	In a simple substance
Temperature range upon storage	Humidity: 20%~90% non dew, condensation -30°C~80°C	In a simple substance

6.2 Electrical property

Item	Value	Note
Maximum voltage	DV5V	
Resistance between terminals	X direction[Film side]:200-600 Ω	
Resistance between terminals	Y direction [Glass side]:300-900Ω	
Insulation resistance	DC 25V 20MΩor above	Connect $X + \sim X$ - and $Y + \sim Y$ -, apply 25VDC Between X and Y for perform measurements
Chattering	10 msec or below	
Rating	Voltage is DC 5V	







6.3 Mechanical property

Item	Performance		Note	
Input method	Used of an exclusive pen or finger			
Load upon operation	Exclusive pen	60-100g or below	Operation and measurement with a pen must be carried out under the following tip conditions: Stylus pen material: POM(ployacetal). Tip: Diameter 3.0mm, SR 0.8 mm	
	Finger	60-100g or below	Operations and measurement methods simulated for a finger must be carried out under the following tip conditions. Material: Silicon rubber (Hardness: 30°Hs) Tip: Diameter 12.0 mm, SR 12.5mm	
Surface hardness	Pencil hardness: 3H or above		It complies with the way of test method JIS K5400.	

6.4 Optical property

Item	Performance	Note
Total light transmittance	80% or above	JIS K7105
Haze	5% or below	JIS K7136
Film specification	Polished type with hard coated surface	



7 Reliability

Test Item	Content of Test	Test Condition	Note	
High Tamparatura Storaga	Endurance test applying the high storage	80°C	2	
High Temperature Storage	temperature for a long time.	96hrs		
Low Tomporoture Storage	Endurance test applying the high storage	-30°C	1,2	
Low Temperature Storage	temperature for a long time.	96hrs		
	Endurance test applying the electric stress	60°C		
High Temperature Operation	(Voltage & Current) and the thermal stress to	96hrs	-	
	the element for a long time.	901118		
Low Temperature Operation	Endurance test applying the electric stress	-20 °C	1	
Low Temperature Operation	under low temperature for a long time.	96hrs		
	The module should be allowed to stand at			
High Temperature/	60°C,90%RH max, for 96hrs under no-load	60°C,90%RH	1,2	
Humidity Operation	condition excluding the polarizer. Then taking	96hrs		
	it out and drying it at normal temperature.			
Thermal Shock Resistance	The sample should be allowed stand the			
Thermal Shock Resistance	following 5 cycles of operation		-	

Note1: No dew condensation to be observed.

Note2: The function test shall be conducted after 4 hours storage at the normal. Temperature and humidity after remove from the rest chamber.

8 Warranty and Conditions

http://www.displaymodule.com/pages/faq HYPERLINK

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